

Part Number: CHP-264

High Power Triple Junction Chip Multi-Mode Fabry-Perot Pulsed Wavelength at 1550nm



Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard Bare Die
- Cost Effective

Application

- Professional Medical
- Laser Rangefinders
- Target Illumination
- Military Systems
- TOF LiDAR for Automotive and Drones



SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

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Specification

CHP-264



Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1550	nm (±20)
Output Power (<10ns)*	P _{out}	35	watts (±10%)
Output Power (150ns)*	P _{out}	17	watts (±10%)
Chip Cavity Length	CL	2500	μm
Emitter Width	W	50	μm
Spectral Width FWHM	Δλ	22	nm 3dB
Slope Efficiency	η	0.8	W/A
Fast Axis Div.	ΘΤ	28	deg FWHM
Slow Axis Div.	Θ	12	deg FWHM
Electrical	Symbol		
Power Conversion Eff.	η	9	%
Operating Current (<10ns)	lop	35	А
Operating Current (150ns)	lop	25	А
Threshold Current	Ітн	0.4	А
Operating Voltage	V _{op}	9	V
Duty Cycle	DC	0.1	%
Mechanical		Range	Units
Operating Temp.**		-40 to 60	°C
Storage Temp.		-40 to 80	°C

*Specified values are rated at a constant heat sink temperature of 20°C.

**High temperature operation will reduce performance and MTTF.

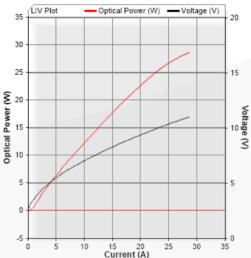
Unless otherwise indicated all values are nominal.



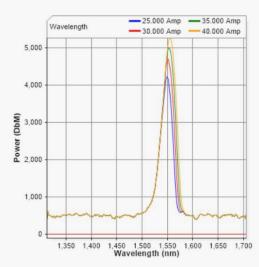
SemiNex Laser Diodes CHP-264

Graphs & Data

Typical CHP L-I-V Characteristics



Typical CHP Output Spectrum



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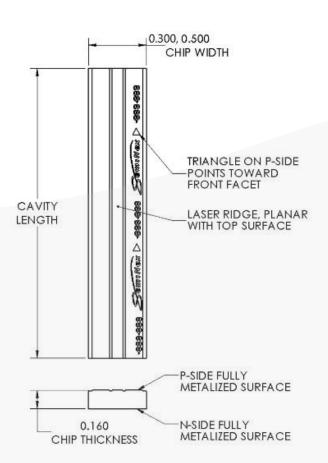
^{*}Tested with 150nsec pulse @ 0.1% Duty Cycle

^{*}Graphs and Data were collected from mounted parts



Mechanical Drawing





CHIP ATTRIBUTES

APERTURE WIDTH (µm)	Single Mode (4, 5) ± 1 Multi Mode (50, 95, 180, 350) ± 3
CHIP WIDTH (µm)	300, 500 ± 10
THICKNESS (µm)	160 ± 10
CAVITY LENGTH (µm)	Varies ± 10

P METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	50	± 10
Pt	125	± 25
Au	250	± 50

N METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	30	± 10
Pt	125	± 25
Au	400	± 40

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